

Features

- Serial Peripheral Interface (SPI) Compatible
- Supports SPI Modes 0 (0,0) and 3 (1,1)
 - Datasheet Describes Mode 0 Operation
- Low-voltage and standard-voltage Operation
 - 1.8V ($V_{CC} = 1.8V$ to 5.5V)
- 20MHz Clock Rate (5V)
- 32-byte Page Mode
- Block Write Protection
 - Protect 1/4, 1/2, or Entire Array
- Write Protect (\overline{WP}) Pin and Write Disable Instructions for Both Hardware and Software Data Protection
- Self-timed Write Cycle (5ms Max)
- High Reliability
 - Endurance: 1,000,000 Write Cycles
 - Data Retention: 100 Years
- Green (Pb/Halide-free/RoHS Compliant) Packaging Options
- Die Sales: Wafer Form, Tape and Reel, and Bumped Wafers

Description

The Atmel® AT25320B/640B provides 32,768-/65,536-bits of Serial Electrically-Erasable Programmable Read-Only Memory (EEPROM) organized as 4,096/8,192 words of 8 bits each. The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operation are essential. The AT25320B/640B is available in space-saving 8-lead JEDEC SOIC, 8-lead TSSOP, 8-lead UDFN, 8-lead XDFN, and 8-ball VFBGA packages.

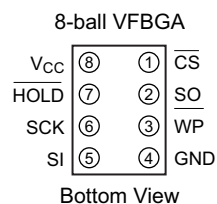
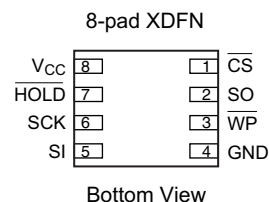
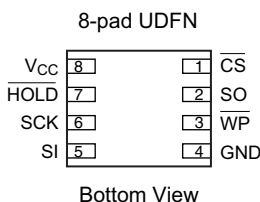
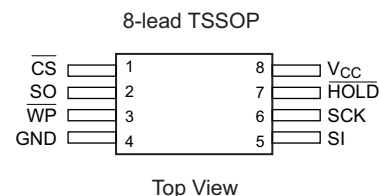
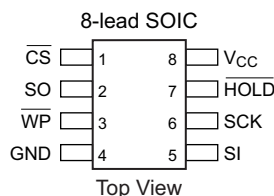
The AT25320B/640B is enabled through the Chip Select pin (\overline{CS}) and accessed via a 3-wire interface consisting of Serial Data Input (SI), Serial Data Output (SO), and Serial Clock (SCK). All programming cycles are completely self-timed, and no separate erase cycle is required before Write.

Block Write Protection is enabled by programming the status register with one of four blocks of write protection. Separate Program Enable and Program Disable instructions are provided for additional data protection. Hardware data protection is provided via the \overline{WP} pin to protect against inadvertent write attempts to the status register. The \overline{HOLD} pin may be used to suspend any serial communication without resetting the serial sequence.

1. Pin Configurations and Pinouts

Table 1-1. Pin Configurations

| Pin Name | Function |
|------------------------|-----------------------|
| $\overline{\text{CS}}$ | Chip Select |
| SCK | Serial Data Clock |
| SI | Serial Data Input |
| SO | Serial Data Output |
| GND | Ground |
| V_{CC} | Power Supply |
| $\overline{\text{WP}}$ | Write Protect |
| HOLD | Suspends Serial Input |



Note: Drawings are not to scale.

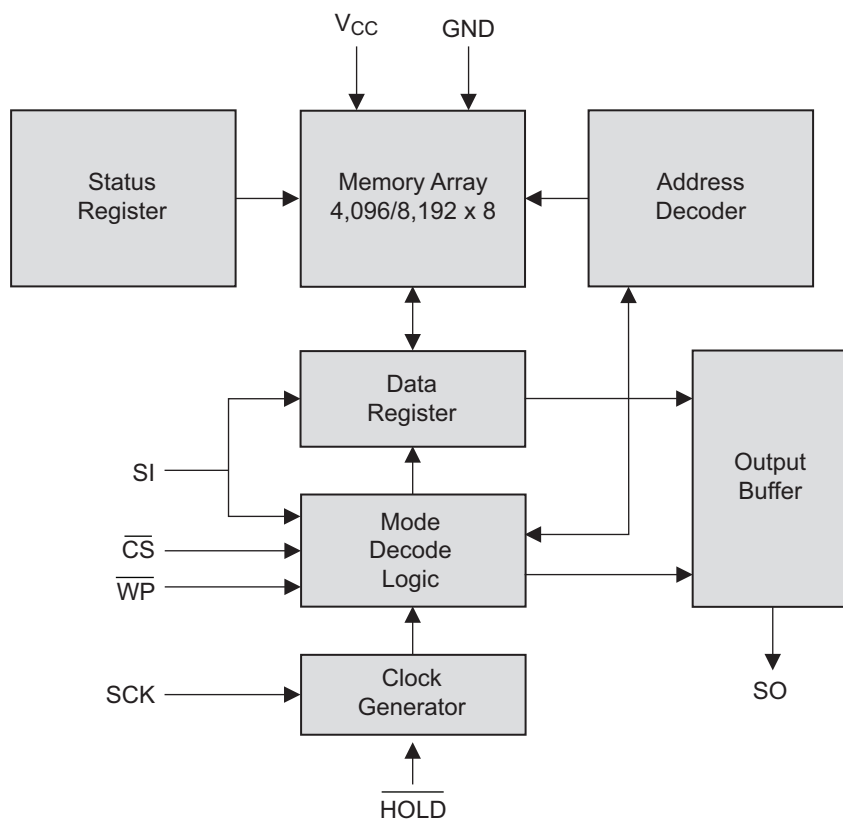
2. Absolute Maximum Ratings*

Operating Temperature -55°C to +125°C
Storage Temperature -65°C to +150°C
Voltage on Any Pin
with Respect to Ground -1.0V to +7.0V
Maximum Operating Voltage 6.25V
DC Output Current 5.0mA

*Notice: Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

3. Block Diagram

Figure 3-1. Block Diagram



4. Electrical Characteristics

4.1 Pin Capacitance

Table 4-1. Pin Capacitance⁽¹⁾

Applicable over recommended operating range from $T_A = 25^\circ\text{C}$, $f = 1.0\text{MHz}$, $V_{CC} = 5.0\text{V}$ (unless otherwise noted).

| Symbol | Test Conditions | Max | Units | Conditions |
|-----------|--|-----|-------|-----------------------|
| C_{OUT} | Output Capacitance (SO) | 8 | pF | $V_{OUT} = 0\text{V}$ |
| C_{IN} | Input Capacitance (\overline{CS} , SCK, SI, \overline{WP} , \overline{HOLD}) | 6 | pF | $V_{IN} = 0\text{V}$ |

Note: 1. This parameter is characterized and is not 100% tested.

4.2 DC Characteristics

Table 4-2. DC Characteristics

Applicable over recommended operating range from: $T_{AI} = -40^\circ\text{C}$ to $+85^\circ\text{C}$, $V_{CC} = 1.8\text{V}$ to 5.5V (unless otherwise noted).

| Symbol | Parameter | Test Condition | Min | Typ | Max | Units |
|----------------|---------------------|---|---------------------|-------|---------------------|---------------|
| V_{CC1} | Supply Voltage | | 1.8 | | 5.5 | V |
| V_{CC2} | Supply Voltage | | 2.5 | | 5.5 | V |
| V_{CC3} | Supply Voltage | | 4.5 | | 5.5 | V |
| I_{CC1} | Supply Current | $V_{CC} = 5.0\text{V}$ at 20MHz, SO = Open, Read | | 7.5 | 10.0 | mA |
| I_{CC2} | Supply Current | $V_{CC} = 5.0\text{V}$ at 20MHz, SO = Open, Read, Write | | 4.0 | 10.0 | mA |
| I_{CC3} | Supply Current | $V_{CC} = 5.0\text{V}$ at 5MHz, SO = Open, Read, Write | | 4.0 | 6.0 | mA |
| I_{SB1} | Standby Current | $V_{CC} = 1.8\text{V}$, $\overline{CS} = V_{CC}$ | | < 0.1 | 6.0 ⁽²⁾ | μA |
| I_{SB2} | Standby Current | $V_{CC} = 2.5\text{V}$, $\overline{CS} = V_{CC}$ | | 0.3 | 7.0 ⁽²⁾ | μA |
| I_{SB3} | Standby Current | $V_{CC} = 5.0\text{V}$, $\overline{CS} = V_{CC}$ | | 2.0 | 10.0 ⁽²⁾ | μA |
| I_{IL} | Input Leakage | $V_{IN} = 0\text{V}$ to V_{CC} | -3.0 | | 3.0 | μA |
| I_{OL} | Output Leakage | $V_{IN} = 0\text{V}$ to V_{CC} , $T_{AC} = 0^\circ\text{C}$ to 70°C | -3.0 | | 3.0 | μA |
| $V_{IL}^{(1)}$ | Input Low-voltage | | -0.6 | | $V_{CC} \times 0.3$ | V |
| $V_{IH}^{(1)}$ | Input High-voltage | | $V_{CC} \times 0.7$ | | $V_{CC} + 0.5$ | V |
| V_{OL1} | Output Low-voltage | $3.6\text{V} \leq V_{CC} \leq 5.5\text{V}$ | | | 0.4 | V |
| V_{OH1} | Output High-voltage | | | | | V |
| V_{OL2} | Output Low-voltage | $1.8\text{V} \leq V_{CC} \leq 3.6\text{V}$ | | | 0.2 | V |
| V_{OH2} | Output High-voltage | | | | | V |

Notes: 1. V_{IL} min and V_{IH} max are reference only and are not tested.
2. Worst case measured at 85°C .

4.3 AC Characteristics

Table 4-3. AC Characteristics

Applicable over recommended operating range from $T_{AI} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = \text{As Specified}$, $CL = 1 \text{ TTL Gate and } 30\text{pF}$ (unless otherwise noted).

| Symbol | Parameter | Voltage | Min | Max | Units |
|-----------|------------------------------|-------------------------------------|-----------------|----------------|---------------|
| f_{SCK} | SCK Clock Frequency | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | 0 0 0 | 20 10 5 | MHz |
| t_{RI} | Input Rise Time | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | | 2 2 2 | μs |
| t_{FI} | Input Fall Time | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | | 2 2 2 | μs |
| t_{WH} | SCK High Time | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | 20 40 80 | | ns |
| t_{WL} | SCK Low Time | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | 20 40 80 | | ns |
| t_{CS} | \overline{CS} High Time | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | 25 50 100 | | ns |
| t_{CSS} | \overline{CS} Setup Time | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | 25 50 100 | | ns |
| t_{CSH} | \overline{CS} Hold Time | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | 25 50 100 | | ns |
| t_{SU} | Data In Setup Time | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | 5 10 20 | | ns |
| t_H | Data In Hold Time | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | 5 10 20 | | ns |
| t_{HD} | \overline{HOLD} Setup Time | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | 5 10 20 | | |
| t_{CD} | \overline{HOLD} Hold Time | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | 5 10 20 | | ns |
| t_V | Output Valid | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | 0 0 0 | 20 40 80 | ns |
| t_{HO} | Output Hold Time | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | 0 0 0 | | ns |

Table 4-3. AC Characteristics (Continued)

Applicable over recommended operating range from $T_{AI} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = \text{As Specified}$, $CL = 1$ TTL Gate and 30pF (unless otherwise noted).

| Symbol | Parameter | Voltage | Min | Max | Units |
|--------------------------|---|-------------------------------------|-----------|-----|--------------|
| t_{LZ} | $\overline{\text{HOLD}}$ to Output Low Z | 4.5 – 5.5 | 0 | 25 | ns |
| | | 2.5 – 5.5 | 0 | 50 | |
| | | 1.8 – 5.5 | 0 | 100 | |
| t_{HZ} | $\overline{\text{HOLD}}$ to Output High Z | 4.5 – 5.5 | | 40 | ns |
| | | 2.5 – 5.5 | | 80 | |
| | | 1.8 – 5.5 | | 200 | |
| t_{DIS} | Output Disable Time | 4.5 – 5.5 | | 40 | ns |
| | | 2.5 – 5.5 | | 80 | |
| | | 1.8 – 5.5 | | 200 | |
| t_{WC} | Write Cycle Time | 4.5 – 5.5 | | 5 | ms |
| | | 2.5 – 5.5 | | 5 | |
| | | 1.8 – 5.5 | | 5 | |
| Endurance ⁽¹⁾ | 3.3V, 25°C, Page Mode | 4.5 – 5.5 2.5 – 5.5 1.8 – 5.5 | 1,000,000 | | Write Cycles |

Note: 1. This parameter is characterized and is not 100% tested.

5. Serial Interface Description

Master: The device that generates the serial clock.

Slave: Because the Serial Clock pin (SCK) is always an input, the AT25320B/640B always operates as a slave.

Transmitter/receiver: The AT25320B/640B has separate pins designated for data transmission (SO) and reception (SI).

MSB: The Most Significant Bit (MSB) is the first bit transmitted and received.

Serial Opcode: After the device is selected with $\overline{\text{CS}}$ going low, the first byte will be received. This byte contains the opcode that defines the operations to be performed.

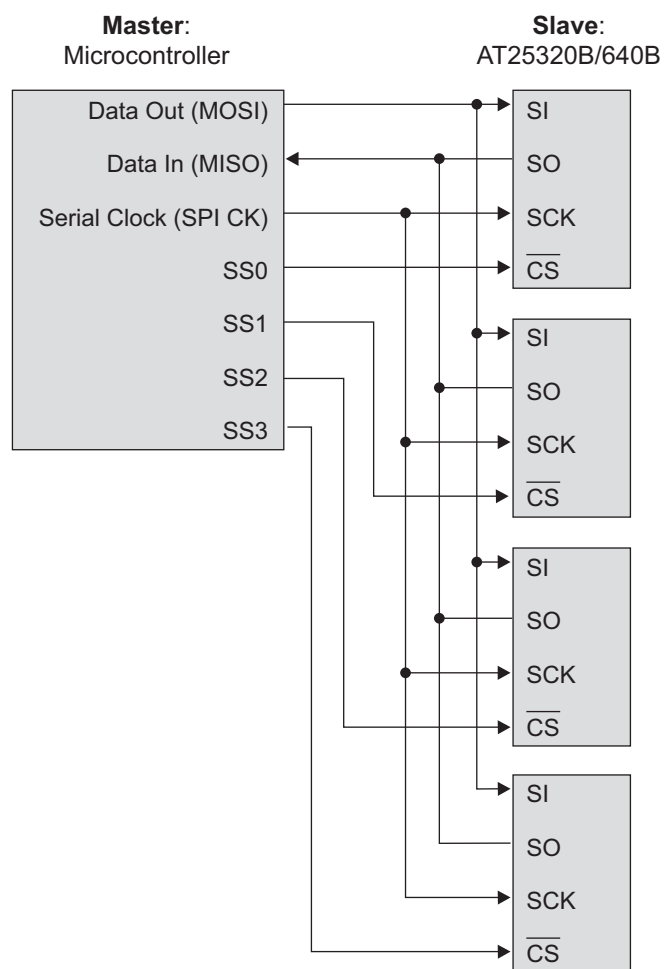
Invalid Opcode: If an invalid opcode is received, no data will be shifted into the AT25320B/640B, and the Serial Output pin (SO) will remain in a high-impedance state until the falling edge of $\overline{\text{CS}}$ is detected again. This will reinitialize the serial communication.

Chip Select: The AT25320B/640B is selected when the $\overline{\text{CS}}$ pin is low. When the device is not selected, data will not be accepted via the SI pin, and the Serial Output pin (SO) will remain in a high-impedance state.

Hold: The $\overline{\text{HOLD}}$ pin is used in conjunction with the $\overline{\text{CS}}$ pin to pause the AT25320B/640B. When the device is selected and a serial sequence is underway, $\overline{\text{HOLD}}$ can be used to pause the serial communication with the master device without resetting the serial sequence. To pause, the $\overline{\text{HOLD}}$ pin must be brought low while the SCK pin is low. To resume serial communication, the $\overline{\text{HOLD}}$ pin is brought high while the SCK pin is low (SCK may still toggle during $\overline{\text{HOLD}}$). Inputs to the SI pin will be ignored while the SO pin is in the high-impedance state.

Write Protect: The Write Protect pin ($\overline{\text{WP}}$) will allow normal read/write operations when held high. When the $\overline{\text{WP}}$ pin is brought low and WPEN bit is one, all write operations to the status register are inhibited. $\overline{\text{WP}}$ going low while $\overline{\text{CS}}$ is still low will interrupt a Write to the status register. If the internal write cycle has already been initiated, $\overline{\text{WP}}$ going low will have no effect on any write operation to the status register. The $\overline{\text{WP}}$ pin function is blocked when the WPEN bit in the status register is zero. This will allow the user to install the AT25320B/640B in a system with the $\overline{\text{WP}}$ pin tied to ground and still be able to write to the status register. All $\overline{\text{WP}}$ pin functions are enabled when the WPEN bit is set to one.

Figure 5-1. SPI Serial Interface



6. Functional Description

The AT25320B/640B is designed to interface directly with the synchronous Serial Peripheral Interface (SPI) of the 6805 and 68HC11 series of microcontrollers.

The AT25320B/640B utilizes an 8-bit instruction register. The list of instructions and their operation codes are contained in [Table 6-1](#). All instructions, addresses, and data are transferred with the MSB first and start with a high-to-low CS transition.

Table 6-1. Instruction Set

| Instruction Name | Instruction Format | Operation |
|------------------|--------------------|-----------------------------|
| WREN | 0000 X110 | Set Write Enable Latch |
| WRDI | 0000 X100 | Reset Write Enable Latch |
| RDSR | 0000 X101 | Read Status Register |
| WRSR | 0000 X001 | Write Status Register |
| READ | 0000 X011 | Read Data from Memory Array |
| WRITE | 0000 X010 | Write Data to Memory Array |

Write Enable (WREN): The device will power-up in the write disable state when V_{CC} is applied. All programming instructions must therefore be preceded by a Write Enable instruction.

Write Disable (WRDI): To protect the device against inadvertent writes, the Write Disable instruction disables all programming modes. The WRDI instruction is independent of the status of the \overline{WP} pin.

Read Status Register (RDSR): The Read Status Register instruction provides access to the status register. The Ready/Busy and Write Enable status of the device can be determined by the RDSR instruction. Similarly, the Block Write Protection Bits indicate the extent of protection employed. These bits are set by using the WRSR instruction.

Table 6-2. Status Register Format

| Bit 7 | Bit 6 | Bit 5 | Bit 4 | Bit 3 | Bit 2 | Bit 1 | Bit 0 |
|-------|-------|-------|-------|-------|-------|-------|------------------|
| WPEN | X | X | X | BP1 | BP0 | WEN | \overline{RDY} |

Table 6-3. Read Status Register Bit Definition

| Bit | Definition |
|---|---|
| Bit 0 (\overline{RDY}) | Bit 0 = 0 (\overline{RDY}) indicates the device is READY. Bit 0 = 1 indicates the write cycle is in progress. |
| Bit 1 (WEN) | Bit 1 = 0 indicates the device is not WRITE ENABLED. Bit 1 = 1 indicates the device is write enabled. |
| Bit 2 (BP0) | See Table 6-4 on page 9 . |
| Bit 3 (BP1) | See Table 6-4 on page 9 . |
| Bits 4 – 6 are zeros when device is not in an internal write cycle. | |
| Bit 7 (WPEN) | See Table 6-5 on page 9 . |
| Bits 0 – 7 are ones during an internal write cycle. | |

Write Status Register (WRSR): The WRSR instruction allows the user to select one of four levels of protection. The AT25320B/640B is divided into four array segments. One-quarter, one-half, or all of the memory segments can be protected. Any of the data within any selected segment will therefore be read-only. The Block Write Protection levels and corresponding status register control bits are shown in [Table 6-4](#).

The three bits BP0, BP1, and WPEN are nonvolatile cells that have the same properties and functions as the regular memory cells (e.g., WREN, t_{WC} , RDSR).

Table 6-4. Block Write Protect Bits

| Level | Status Register Bits | | Array Addresses Protected | |
|--------|----------------------|-----|---------------------------|-----------|
| | BP1 | BP0 | AT25320B | AT25640B |
| 0 | 0 | 0 | None | None |
| 1(1/4) | 0 | 1 | 0C00–0FFF | 1800–1FFF |
| 2(1/2) | 1 | 0 | 0800–0FFF | 1000–1FFF |
| 3(All) | 1 | 1 | 0000–0FFF | 0000–1FFF |

The WRSR instruction also allows the user to enable or disable the Write Protect (\overline{WP}) pin through the use of the Write Protect Enable (WPEN) bit. Hardware Write Protection is enabled when the \overline{WP} pin is low and the WPEN bit is one. Hardware Write Protection is disabled when either the \overline{WP} pin is high or the WPEN bit is zero. When the device is hardware write protected, writes to the status register, including the Block Protect bits and the WPEN bit, and the block-protected sections in the memory array are disabled. Writes are only allowed to sections of the memory that are not block-protected.

Note: When the WPEN bit is Hardware Write Protected, it cannot be changed back to zero as long as the \overline{WP} pin is held low.

Table 6-5. WPEN Operation

| WPEN | \overline{WP} | WEN | Protected Blocks | Unprotected Blocks | Status Register |
|------|-----------------|-----|------------------|--------------------|-----------------|
| 0 | X | 0 | Protected | Protected | Protected |
| 0 | X | 1 | Protected | Writeable | Writeable |
| 1 | Low | 0 | Protected | Protected | Protected |
| 1 | Low | 1 | Protected | Writeable | Protected |
| X | High | 0 | Protected | Protected | Protected |
| X | High | 1 | Protected | Writeable | Writeable |

Read Sequence (READ): Reading the AT25320B/640B via the Serial Output (SO) pin requires the following sequence. After the \overline{CS} line is pulled low to select a device, the Read opcode is transmitted via the SI line followed by the byte address to be read (A15 – A0, see Table 6-6). Upon completion, any data on the SI line will be ignored. The data (D7 – D0) at the specified address is then shifted out onto the SO line. If only one byte is to be read, the \overline{CS} line should be driven high after the data comes out. The read sequence can be continued since the byte address is automatically incremented and data will continue to be shifted out. When the highest address is reached, the address counter will roll over to the lowest address allowing the entire memory to be read in one continuous read cycle.

Write Sequence (WRITE): In order to program the AT25320B/640B, two separate instructions must be executed. First, the device **must be write enabled** via the WREN instruction. Then a Write instruction may be executed. Also, the address of the memory location(s) to be programmed must be outside the protected address field location selected by the Block Write Protection level. During an internal write cycle, all commands will be ignored except the RDSR instruction.

A Write instruction requires the following sequence. After the \overline{CS} line is pulled low to select the device, the Write opcode is transmitted via the SI line followed by the byte address (A15 – A0) and the data (D7 – D0) to be programmed (see Table 6-6). Programming will start after the \overline{CS} pin is brought high. The low-to-high transition of the \overline{CS} pin must occur during the SCK low-time immediately after clocking in the D0 (LSB) data bit.

The Ready/Busy status of the device can be determined by initiating a Read Status Register (RDSR) instruction. If Bit 0 = 1, the write cycle is still in progress. If Bit 0 = 0, the write cycle has ended. Only the RDSR instruction is enabled during the write programming cycle.

The AT25320B/640B is capable of a 32-byte page write operation. After each byte of data is received, the five low-order address bits are internally incremented by one; the high-order bits of the address will remain constant. If more than 32-bytes of data are transmitted, the address counter will rollover and the previously written data will be overwritten. The AT25320B/640B is automatically returned to the write disable state at the completion of a write cycle.

Note: If the device is not Write-enabled (WREN), the device will ignore the write instruction and will return to the standby state, when \overline{CS} is brought high. A new \overline{CS} falling edge is required to reinitiate the serial communication.

Table 6-6. Address Key

| Address | AT25320B | AT25640B |
|-----------------|-----------------|-----------------|
| A_N | $A_{11}-A_0$ | $A_{12}-A_0$ |
| Don't Care Bits | $A_{15}-A_{12}$ | $A_{15}-A_{13}$ |

7. Timing Diagrams

Figure 7-1. Synchronous Data Timing (for Mode 0)

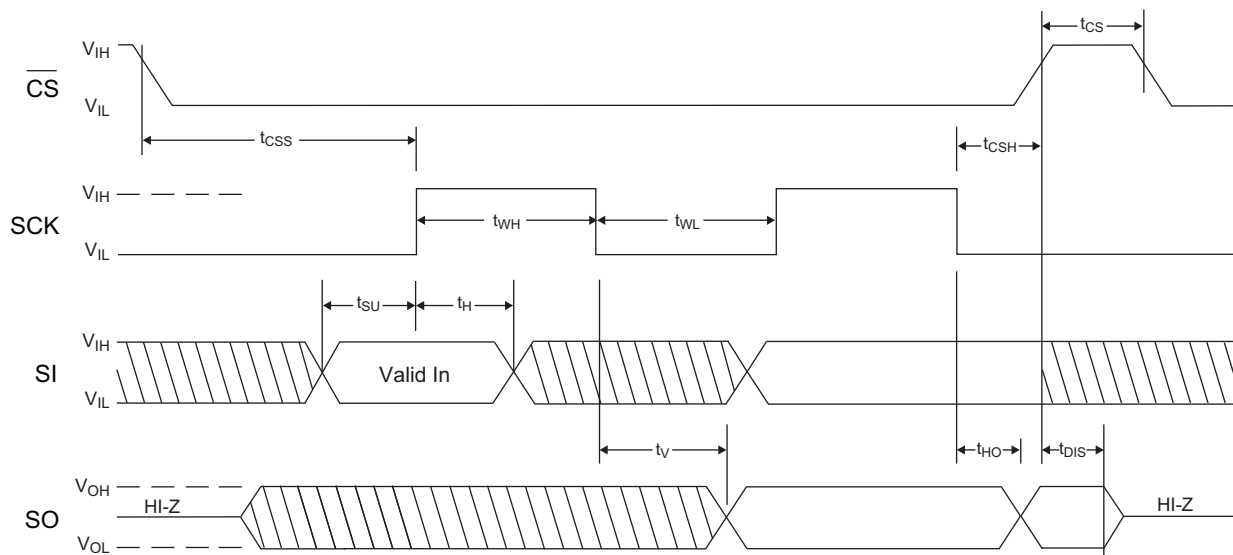


Figure 7-2. WREN Timing

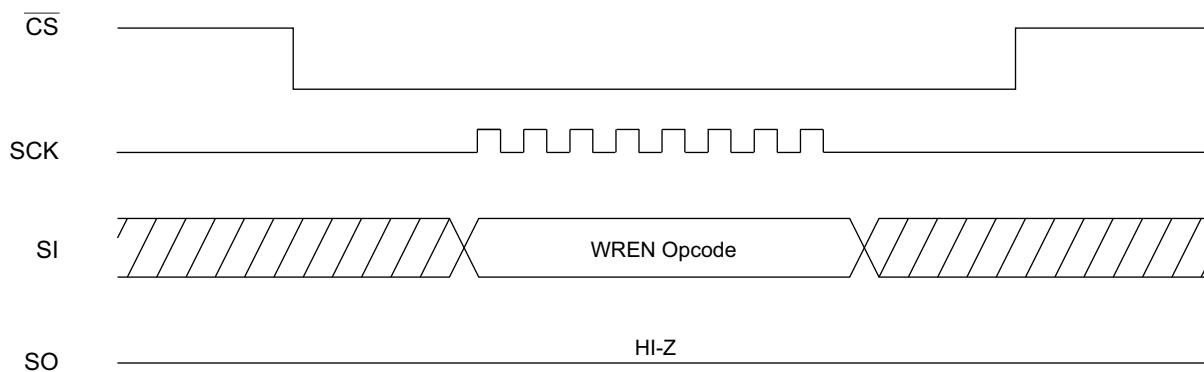


Figure 7-3. WRDI Timing

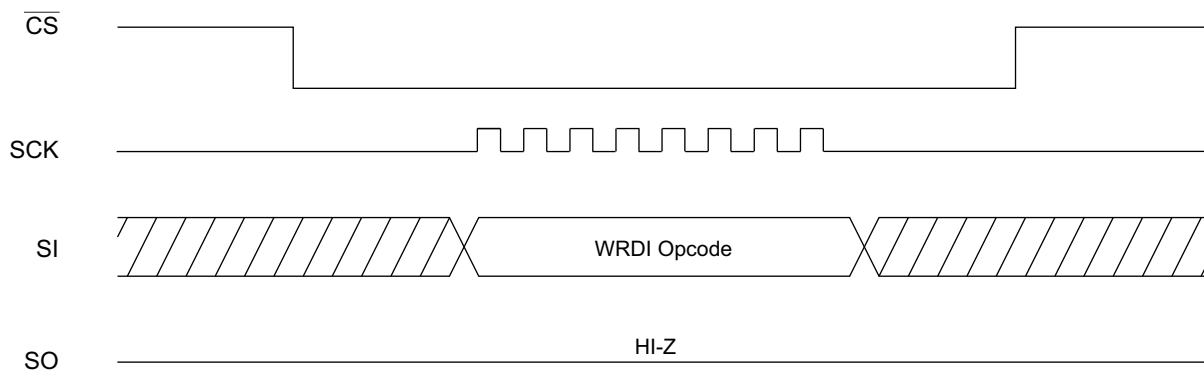


Figure 7-4. RDSR Timing

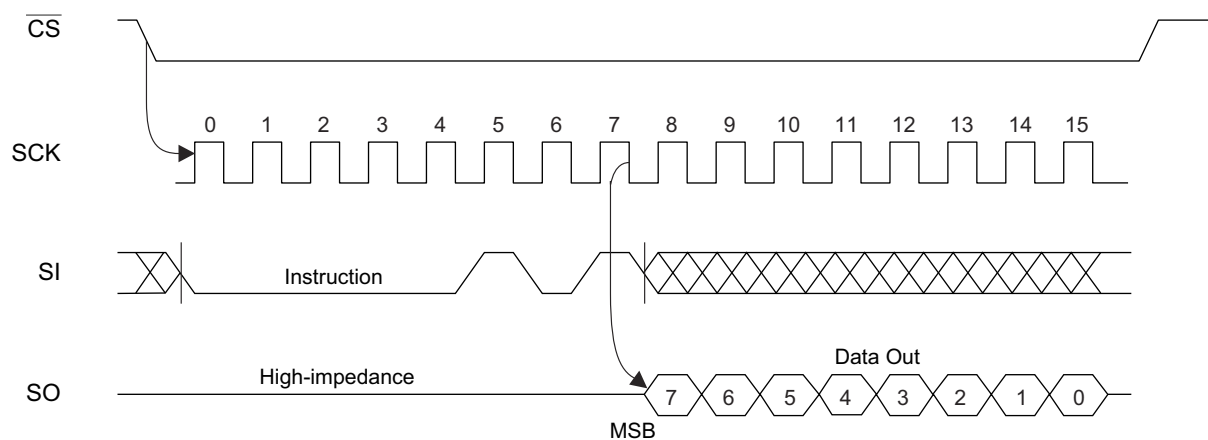


Figure 7-5. WRSR Timing

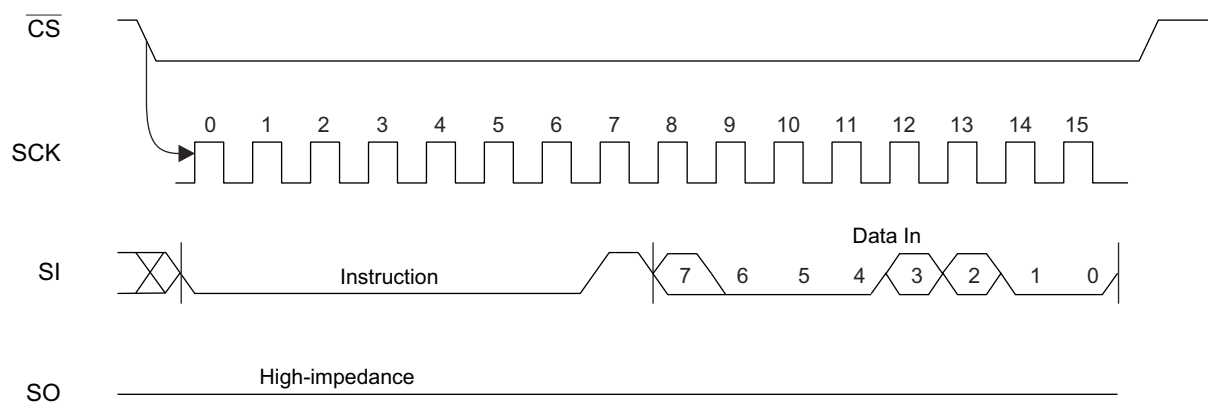


Figure 7-6. Read Timing

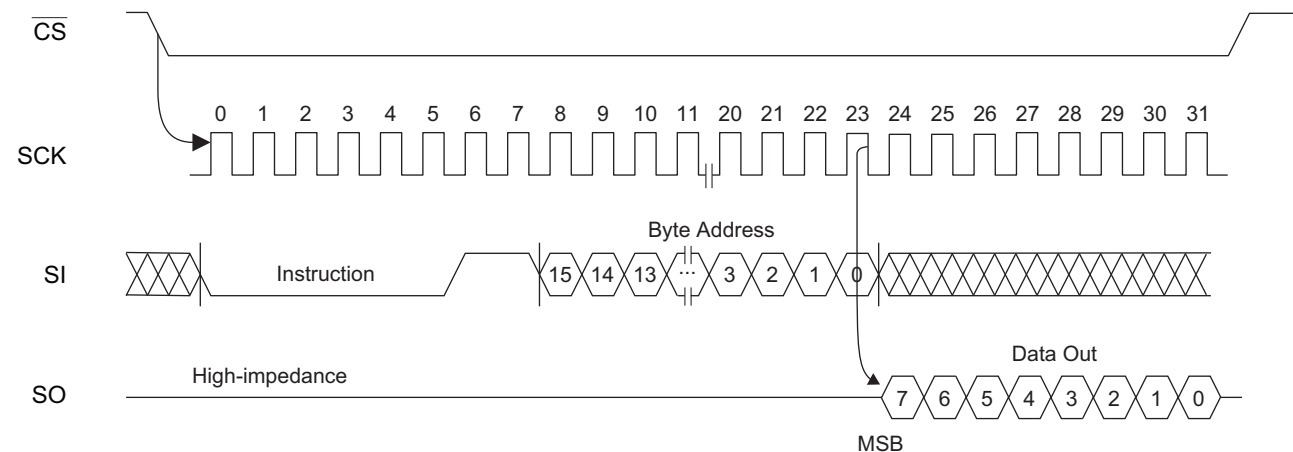


Figure 7-7. Write Timing

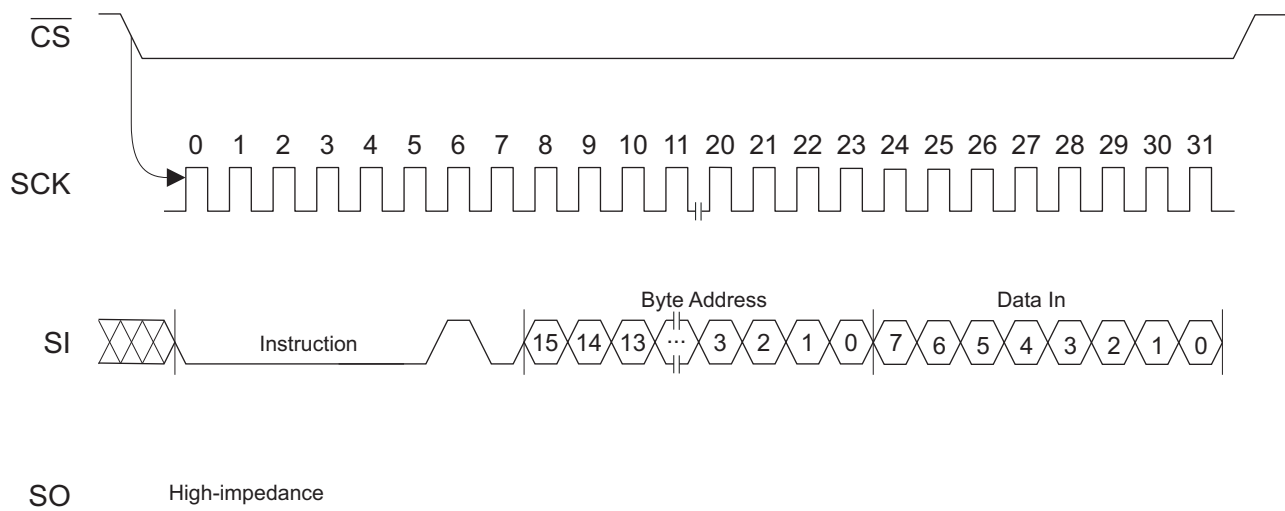
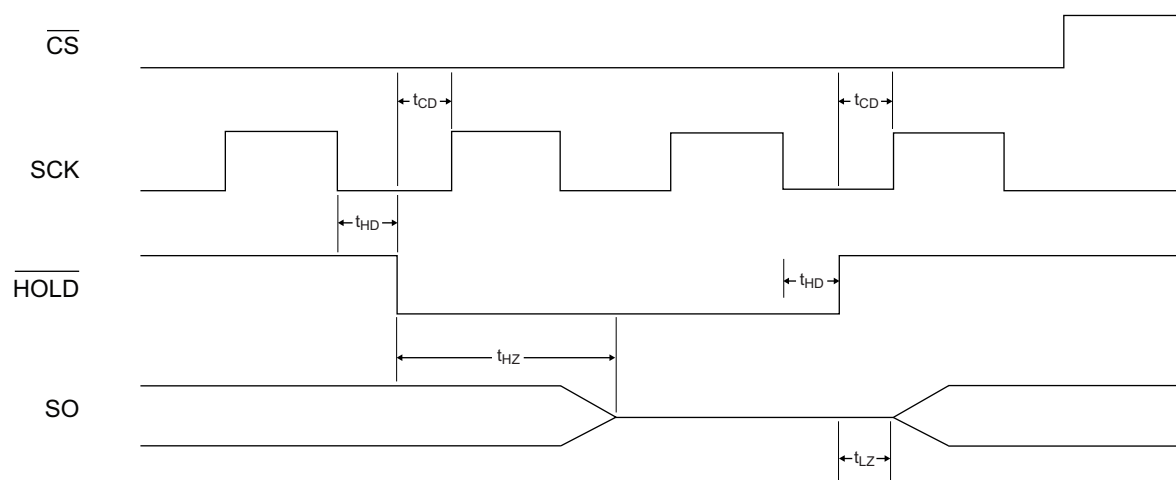
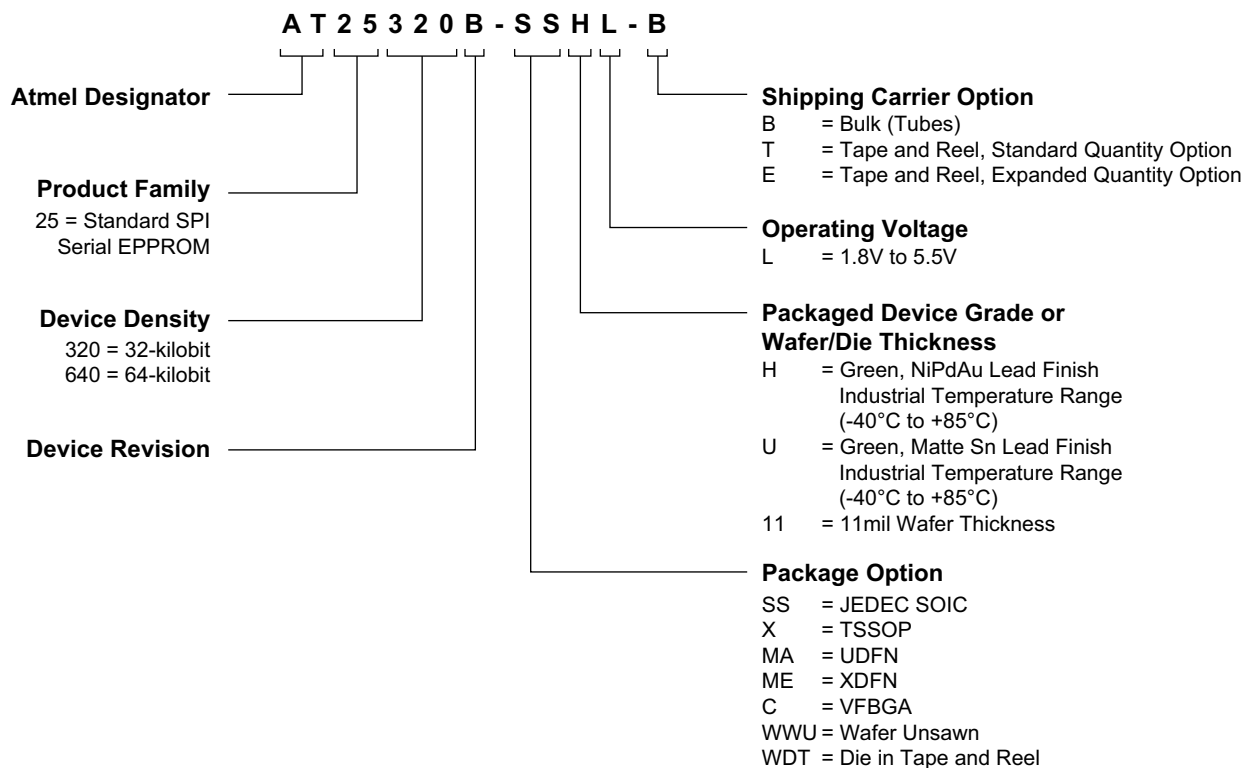


Figure 7-8. HOLD Timing

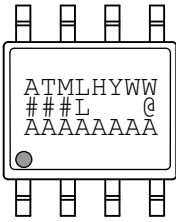
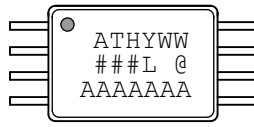
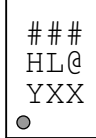
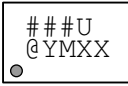



8. Ordering Code Detail



9. Part Markings

AT25320B and AT25640B: Package Marking Information


| | | |
|---|--|--|
| 8-lead SOIC  | 8-lead TSSOP  | 8-lead UDFN 2.0 x 3.0 mm Body  |
| 8-ball VFBGA 2.35 x 3.73 mm Body  | 8-lead XDFN 1.8 x 2.2 mm Body  | |

Note 1: ● designates pin 1

Note 2: Package drawings are not to scale

| Catalog Number Truncation | | | |
|--|-------------|----------------------------------|---|
| AT25320B | | Truncation Code ###: 5BB | |
| AT25640B | | Truncation Code ###: 5CB | |
| Date Codes | | | Voltages |
| Y = Year | M = Month | WW = Work Week of Assembly | L: 1.8V min |
| 2: 2012 6: 2016 | A: January | 02: Week 2 | |
| 3: 2013 7: 2017 | B: February | 04: Week 4 | |
| 4: 2014 8: 2018 | ... | ... | |
| 5: 2015 9: 2019 | L: December | 52: Week 52 | |
| Country of Assembly | | Lot Number | Grade/Lead Finish Material |
| @ = Country of Assembly | | AAA...A = Atmel Wafer Lot Number | U: Industrial/Matte Tin H: Industrial/NiPdAu |
| Trace Code | | | Atmel Truncation |
| XX = Trace Code (Atmel Lot Numbers Correspond to Code) Example: AA, AB.... YZ, ZZ | | | AT: Atmel ATM: Atmel ATML: Atmel |

11/5/12

| | | | |
|---|---|--------------|------|
|  Package Mark Contact: DL-CSO-Assy_eng@atmel.com | TITLE | DRAWING NO. | REV. |
| | 25320-640BSM, AT25320B and AT25640B Package Marking Information | 25320-640BSM | B |

10. Ordering Information

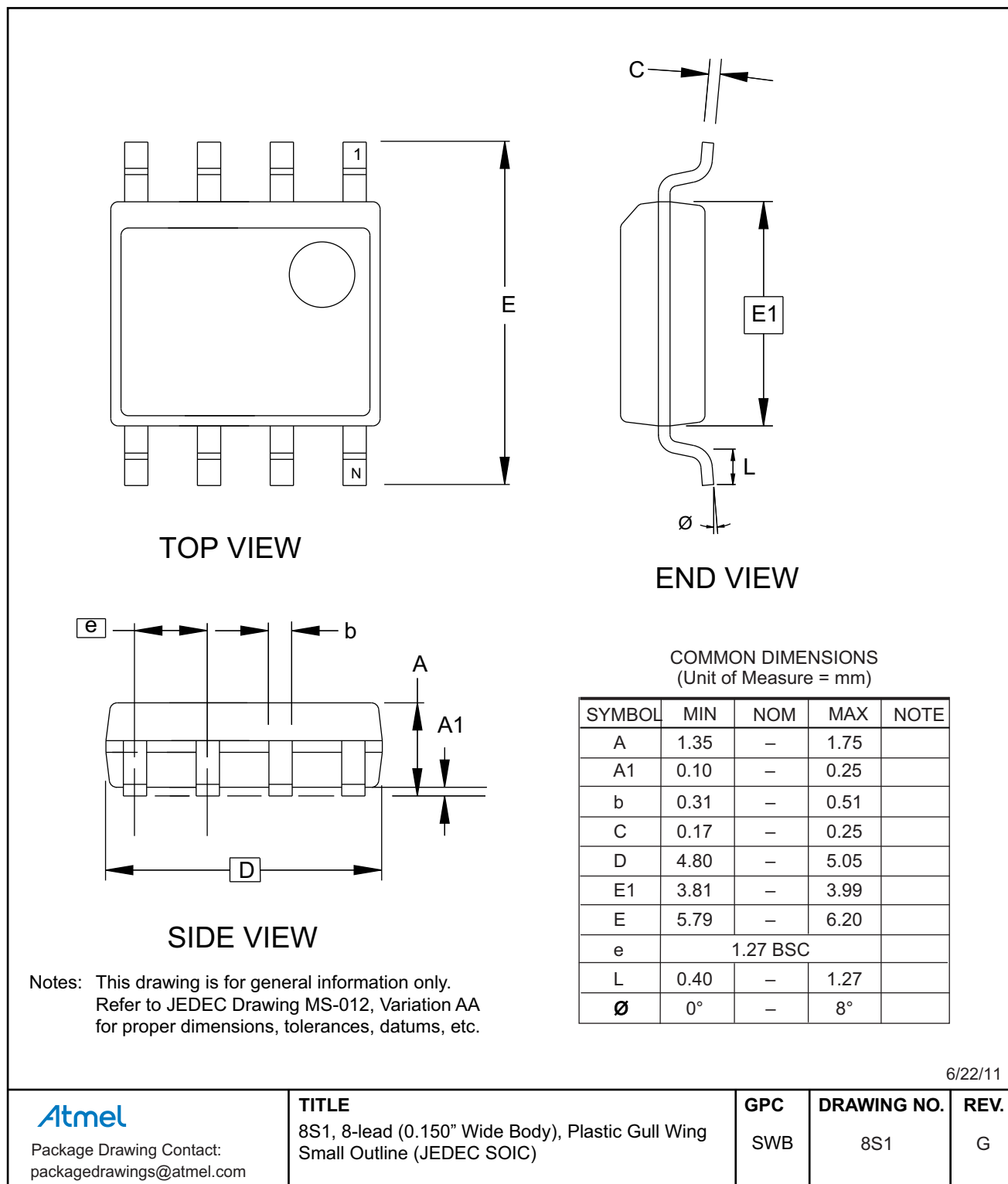
| Atmel Ordering Code | Lead Finish | Package | Delivery Information | | Operation Range |
|--------------------------------|------------------------------------|------------|----------------------|-----------------|---|
| | | | Form | Quantity | |
| AT25320B-SSHL-B | NiPdAu (Lead-free/Halogen-free) | 8S1 | Bulk (Tubes) | 100 per Tube | Industrial Temperature (-40°C to 85°C) |
| AT25320B-SSHL-T | | | Tape and Reel | 4,000 per Reel | |
| AT25320B-XHL-B | | 8X | Bulk (Tubes) | 100 per Tube | |
| AT25320B-XHL-T | | | Tape and Reel | 5,000 per Reel | |
| AT25320B-MAHL-T | | 8MA2 | Tape and Reel | 5,000 per Reel | |
| AT25320B-MAHL-E | | | Tape and Reel | 15,000 per Reel | |
| AT25320B-MEHL-T | | 8ME1 | Tape and Reel | 5,000 per Reel | |
| AT25320B-CUL-T | SnAgCu (Lead-free/Halogen-free) | 8U2-1 | Tape and Reel | 5,000 per Reel | |
| AT25320B-WWU11L ⁽¹⁾ | N/A | Wafer Sale | Note 1 | | |
| AT25640B-SSHL-B | NiPdAu (Lead-free/Halogen-free) | 8S1 | Bulk (Tubes) | 100 per Tube | Industrial Temperature (-40°C to 85°C) |
| AT25640B-SSHL-T | | | Tape and Reel | 4,000 per Reel | |
| AT25640B-XHL-B | | 8X | Bulk (Tubes) | 100 per Tube | |
| AT25640B-XHL-T | | | Tape and Reel | 5,000 per Reel | |
| AT25640B-MAHL-T | | 8MA2 | Tape and Reel | 5,000 per Reel | |
| AT25640B-MAHL-E | | | Tape and Reel | 15,000 per Reel | |
| AT25640B-MEHL-T | | 8ME1 | Tape and Reel | 5,000 per Reel | |
| AT25640B-CUL-T | SnAgCu (Lead-free/Halogen-free) | 8U2-1 | Tape and Reel | 5,000 per Reel | |
| AT25640B-WWU11L ⁽¹⁾ | N/A | Wafer Sale | Note 1 | | |

Note: 1. Contact Atmel Sales for Wafer sales

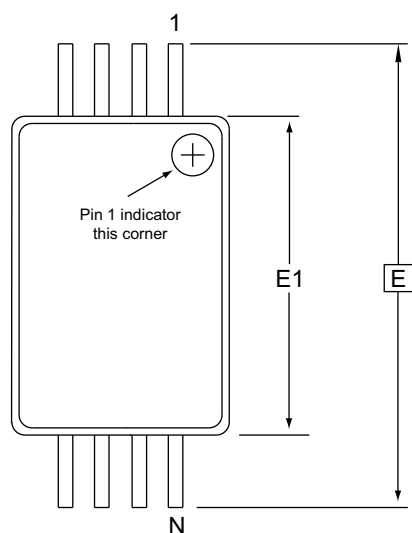
| Package Type | |
|--------------|--|
| 8S1 | 8-lead, 0.15" wide, Plastic Gull Wing Small Outline (JEDEC SOIC) |
| 8X | 8-lead, 4.40mm body, Plastic Thin Shrink Small Outline Package (TSSOP) |
| 8MA2 | 8-pad, 2.00mm x 3.00mm body, 0.50mm pitch, Ultra Thin, Dual No Lead (UDFN) |
| 8ME1 | 8-pad, 1.80mm x 2.20mm body, Ultra Lead Frame Land Grid Array (XDFN) |
| 8U2-1 | 8-ball, 2.35mm x 3.73mm body, 0.75mm pitch (VFBGA) |

11. Packaging Information

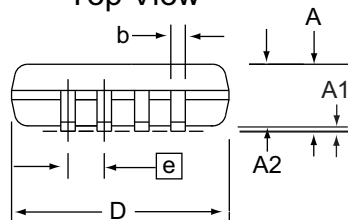
11.1 8S1 — 8-lead JEDEC SOIC



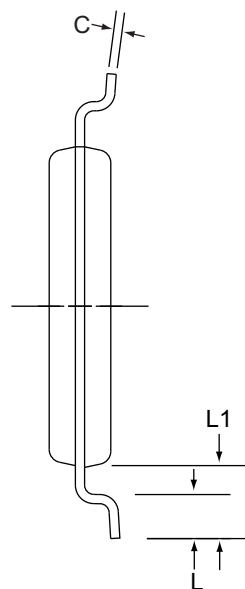
11.2 8X — 8-lead TSSOP



Top View



Side View



End View

COMMON DIMENSIONS
(Unit of Measure = mm)

| SYMBOL | MIN | NOM | MAX | NOTE |
|--------|----------|------|------|------|
| A | - | - | 1.20 | |
| A1 | 0.05 | - | 0.15 | |
| A2 | 0.80 | 1.00 | 1.05 | |
| D | 2.90 | 3.00 | 3.10 | 2, 5 |
| E | 6.40 BSC | | | |
| E1 | 4.30 | 4.40 | 4.50 | 3, 5 |
| b | 0.19 | 0.25 | 0.30 | 4 |
| e | 0.65 BSC | | | |
| L | 0.45 | 0.60 | 0.75 | |
| L1 | 1.00 REF | | | |
| C | 0.09 | - | 0.20 | |

- Notes:
1. This drawing is for general information only. Refer to JEDEC Drawing MO-153, Variation AA, for proper dimensions, tolerances, datums, etc.
 2. Dimension D does not include mold Flash, protrusions or gate burrs. Mold Flash, protrusions and gate burrs shall not exceed 0.15mm (0.006in) per side.
 3. Dimension E1 does not include inter-lead Flash or protrusions. Inter-lead Flash and protrusions shall not exceed 0.25mm (0.010in) per side.
 4. Dimension b does not include Dambar protrusion. Allowable Dambar protrusion shall be 0.08mm total in excess of the b dimension at maximum material condition. Dambar cannot be located on the lower radius of the foot. Minimum space between protrusion and adjacent lead is 0.07mm.
 5. Dimension D and E1 to be determined at Datum Plane H.

2/27/14

Atmel

Package Drawing Contact:
packagedrawings@atmel.com

TITLE

8X, 8-lead 4.4mm Body, Plastic Thin
Shrink Small Outline Package (TSSOP)

GPC

TNR

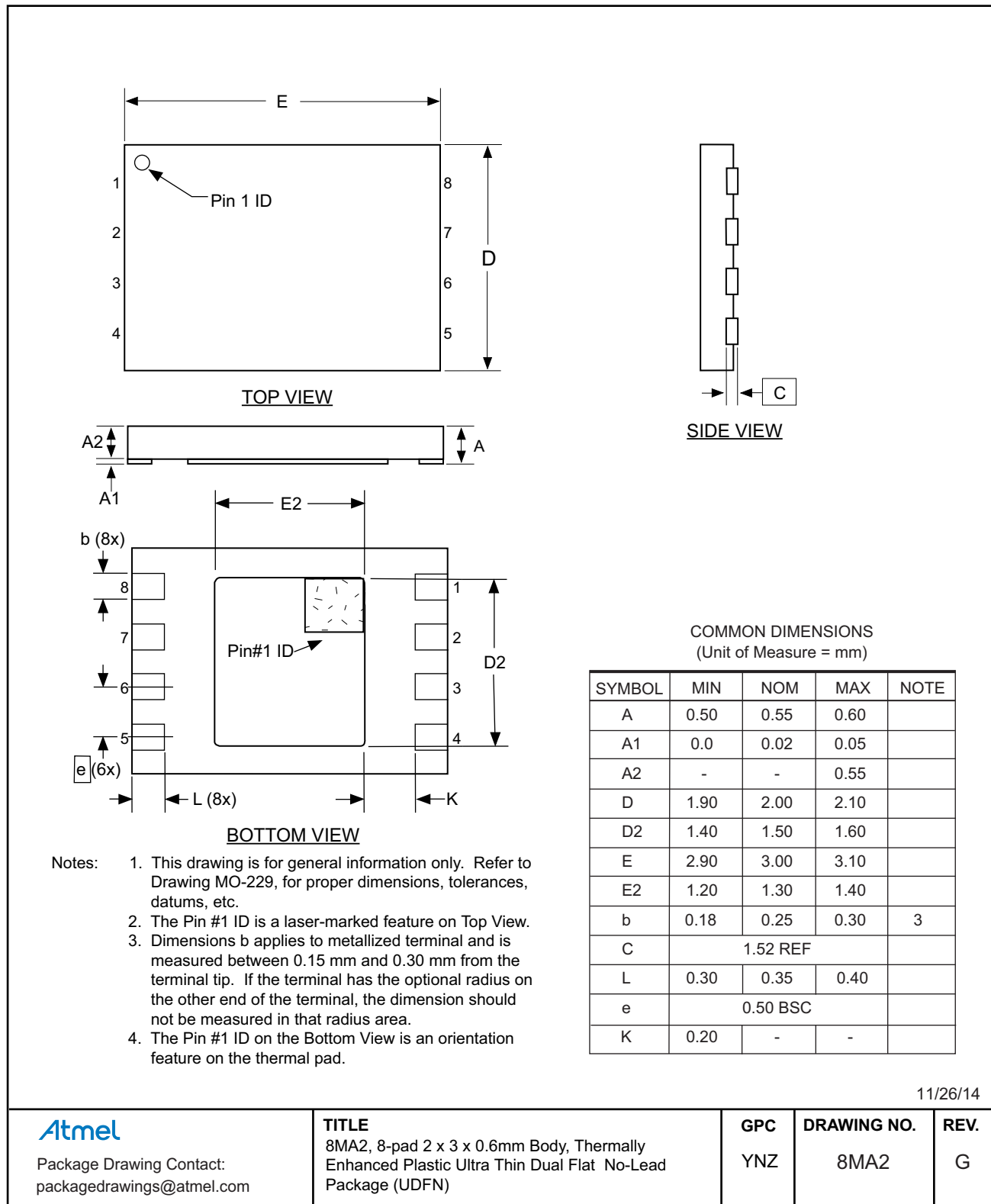
DRAWING NO.

8X

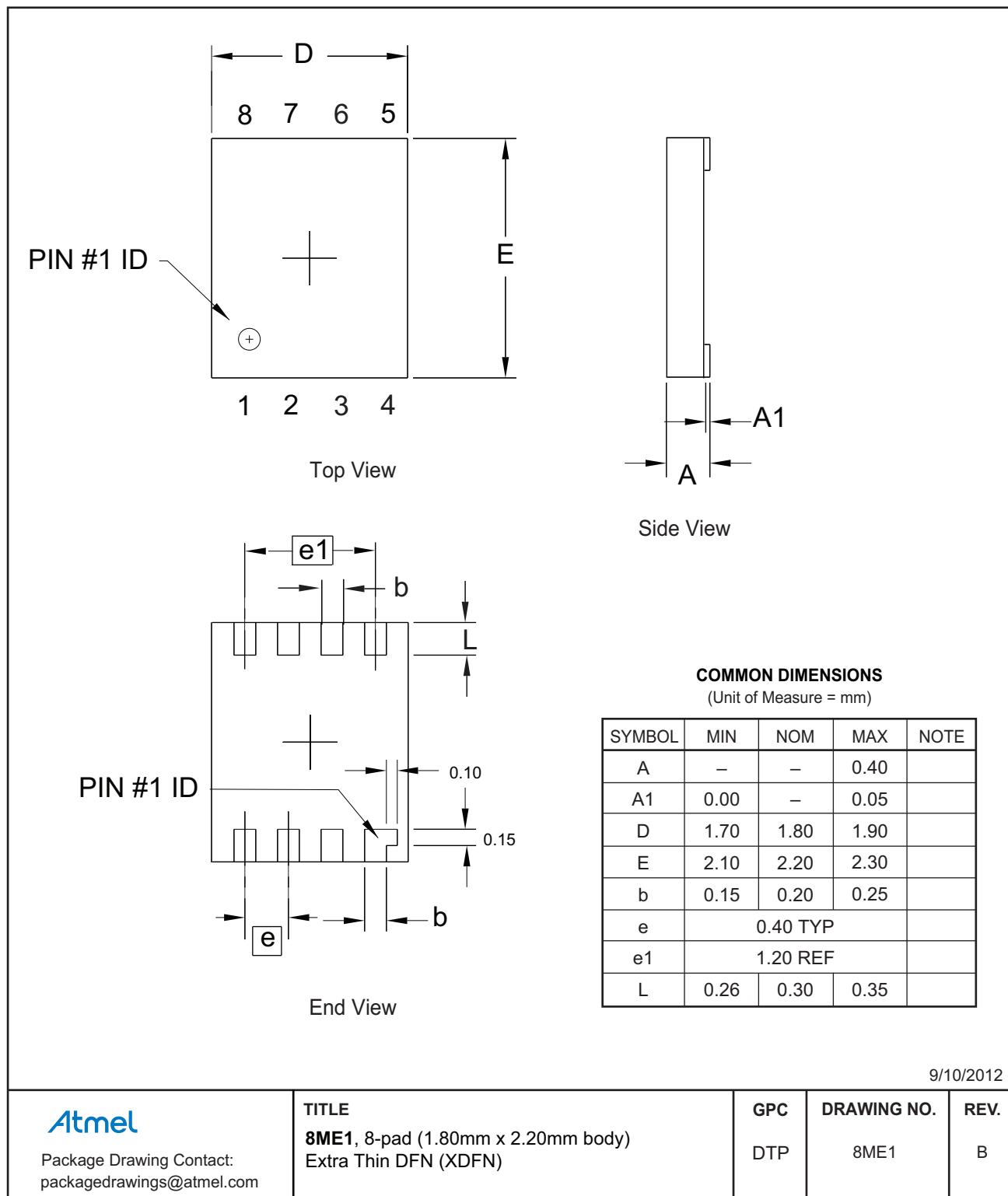
REV.

E

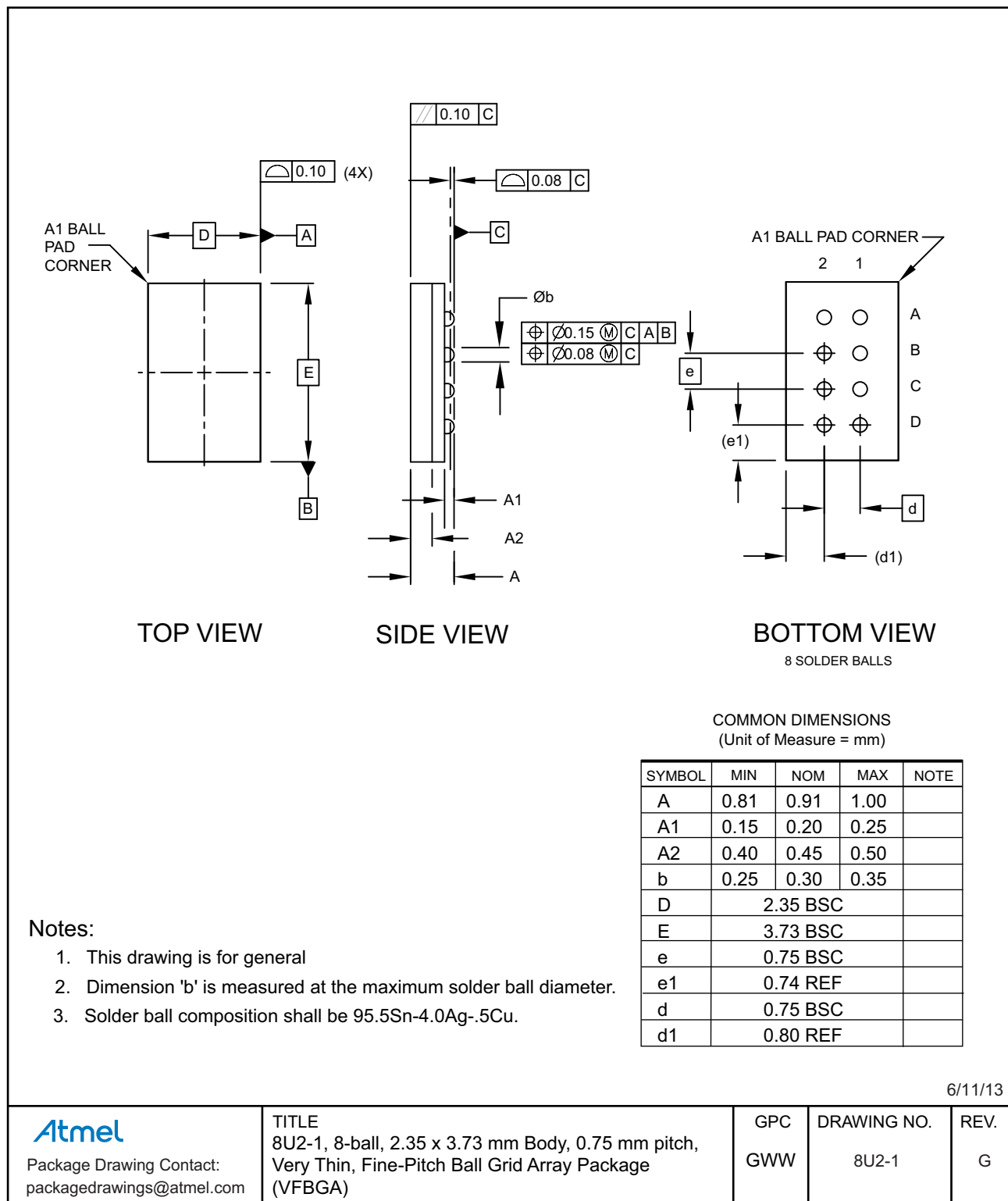
11.3 8MA2 — 8-pad UDFN



11.4 8ME1 — 8-pad XDFN



11.5 8U2-1 — 8-ball VFBGA



12. Revision History

| Doc. Rev. | Date | Comments |
|-----------|---------|---|
| 8535H | 01/2015 | Add the UDFN Expanded Quantity Option. Update the 8X, 8MA2, and 8ME1 package outline drawings and the ordering information. |
| 8535G | 11/2012 | Update part markings to single page part marking. Update package drawings. Replace 8A2 package with 8X package. Update template and Atmel logos. |
| 8535F | 06/2010 | Update 8A2 and 8S1 package drawings. Remove Preliminary. |
| 8535E | 04/2010 | Update Ordering Code Detail, Ordering Information, template. |
| 8535D | 08/2009 | Change Catalog Numbering. Add new Part Marking Information. |
| 8535C | 05/2009 | Add Part Marking information; changed to Preliminary status. |
| 8535B | 07/2008 | Modify 'Endurance' parameter on page 6. |
| 8535A | 04/2008 | Initial document release. |



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

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- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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